Calculations of near-field emissions in frequency-domain into timedependent data with arbitrary wave form transient perturbations

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Abstract

This paper is devoted on the application of a computational method for calculating transient electromagnetic (EM) nearfield (NF) radiated by el ectronic s tructures excited b y arbitrary wave f orm p erturbations i(t) f rom frequencydependent data. T he m ethod pr oposed is ba sed on t he applications of fast Fourier tr ansform (FFT). T he s teps illustrating the proposed method principle are described. It is based on three successive steps: the synchronization of the input excitation spectrum I(f) and the given frequency NF data $H_0(f)$, the convolution of inputs data and then, the determination of the time-domain NF emissions H(t). The method feasibility is verified by simulations from EM3D standard tools. In addition, a time-frequency extraction technique of the time-dependent z-transversal NF component $X_z(t)$ from the frequency-dependent longitudinal components $X_x(f)$ and $X_y(f)$ is also presented. This technique is b ased on t he conjugation of t he p lane wave spectrum (PWS) transform and FFT. Verification with NF radiated by a set of dipole radiations is made. The method introduced in this paper is particularly useful for investigating timedomain e missions f or E MC a pplications by c onsidering transient EM interferences (EMIs).

Keywords: Near-field (NF) emission, transient perturbations, electromagnetic compatibility (EMC), FFT, plane wave spectrum (PWS), time-frequency method, timedomain computational method.

1. Introduction

With t he unintentional e lectromagnetic interferences (EMIs), the design engineers needs to take into account the electromagnetic c ompatibility (EMC) models during t he electronic s ystems manufacture p rocess [1-3]. The most disturbing E MC effects ca used b y the electrical/electronic system integration can b e due t o the E M n ear-field (NF) radiations and the couplings b etween the different circuits

as t he el ectrical cab les and el ectronic eq uipments [4-5]. Therefore, NF emission models and scanning measurement techniques were proposed [6-9]. Nevertheless, large amount of the NF investigation were performed in f requencydomain. H owever, the t ransient perturbations a re susceptible to degrade the mixed electronic s ystems as digital a nd r adio f requencies (RFs) [10] and i ntegrated systems [11]. It has been found that the EMC engineering should include the transient EM-NF emissions especially in time-domain [10-20]. Currently, this topic attracts many of electronic engineers and r esearchers. With the increase of integration density and the operating rate, EM NF analysis is necessary for the RF/digital electronic boards [1-3]. Undesired transient effects can be created by different perturbations a s t he no n-linearity o f electronic devices during their commutations [10]. These transient E M-field emissions need to be canceled out for the reliability. For this reason, E M transient a nalysis is required. A s r eported i n [21], analog/mixed (AM) electronic designers use regularly software t ools s uch a s S PICE, while t hose working on RF/microwave engineering focus i n f requency-domain simulation tools based on the S-parameters. In practice, one needs the fusion of both approaches as AM engineers are required to make further analysis on the critical components by using EM simulation tools. This constitutes an improvement technique in the EMC area. In this optic, the EM emission modeling by the mixed components becomes one of the crucial steps before the implementation. Therefore, the issues both in frequency- and time-domains should be forecasted.

Basically, the transient EM-field computation was initially determined with elementary EM dipole radiations [22-27]. As reported in [7-8], an y el ectronic ci rcuit NF r adiations can b e r eproduced with arrays of elementary dipoles. Moreover, time-domain NF radiation was al so conducted with excitation b ased on t he ar bitrary wave form signals [28]. This computational approach is advantageous for the modeling of E MN F r adiated by c omplex electrical/electronic s tructures which cannot be modeled with most of standard tools [29-30]. This computation

method r emains complicated when c onsidering electronic devices operating with UWB and base band s ignal. So, more r ecently, E M c omputational method based on t he plane wave spectrum (PWS) theory was proposed [31-33]. This method is based on the exploitation of the fundamental plane wave's properties and FFT, then, transposed in timedomain. I t a llows simplifying considerably t he reconstruction of the EM NF radiations (including the evanescent waves) as t he cal culation o fl ongitudinal component (along z -axis) from t ransversal c omponents (along x - and y -axes) [31-32], the NF/NF transform [33] and al so extraction of the el ectric NF components (E_x , E_y and E_z) from 2D data H_x and H_y [34]. In the continuation of these works, a s a special is sue of [35], the generalized methodology of a time-frequency EMNF computation is presented in this paper.

The paper is mainly divided in three sections. Section 2 is focused on the application of the routine algorithm of EM NF time-frequency method proposed in [28][35]. Section 3 introduces a time-domain EM c omputation method based on the PWS transform for extracting EM NF component X_z from X_x and X_y with a rbitrary excitations. Section 4 is the conclusion.

2. Calculation method of time-dependent nearfield maps with transient perturbations from frequency-dependent data

This s ection d escribes th e time-frequency computation methodology presented in th is. T he basic theoretical approach and the r outine a lgorithm are d etailed. In t his paper, w e will e xtend t he FFT a nd I FFT i nstructions to reconstitute the t ime-dependent m agnetic NF m aps $H_{x,y,z}(t)$ radiated b y an el ectronic device f rom t he frequency components $H_{x,y,z}(f)$ for any excitation undesired currents or voltages for the EMC applications as proposed in [28][35].

2.1. Theoretical approach of the time-frequency computation method understudy

Let us c onsider the time-dependent pl ot of t he a rbitrary signal x(t) presented in Figure 1. This signal is supposed as the excitation of t he electronics tructure under consideration. As indicated in this figure, the sampled data corresponding t ot he signal under t est is supposed and discretized from the starting time t_{min} to the stop time t_{max} with time step Δt . It means t hat the number of t imedependent samples is equal to:

$$n = \operatorname{int}\left(\frac{t_{\max} - t_{\min}}{\Delta t}\right),\tag{1}$$

with $int(\alpha)$ generates the lowest integer number greater than the real number α .

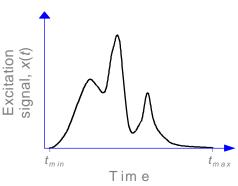


Figure 1: Transient excitation signal.

By definition, we can determine mathematically the frequency-dependent spectrum of i(t) as a complex number denoted as:

$$\underline{I}(f_k) = fft[\underline{i}(t_k)], \qquad (2)$$

where $t_k = k \cdot \Delta t$ and $k = \{1 \cdots n\}$. In this expression, the variable f_k represents the s ampling of the frequency variable. These f requencies can be extracted f rom the sampling time parameters by the following expression:

$$f_k = k \cdot \Delta f \,, \tag{3}$$

with $k = \{1 \cdots n\}$ and Δf is the step f requency which is determined by the relation:

$$\Delta f = \frac{1}{t_{\max} - t_{\min}} \,. \tag{4}$$

In order to operate with the excitation signal, the frequency spectrum magnitude n eeds to be n ormalized as a complex coefficient. F or this r eason, \underline{I}_0 is as sumed as a h armonic component sinusoidal c urrent n ecessary for g enerating the electric or magnetic field spectrum $\underline{H}_0(f)$, the harmonics of the input cu rrent can be n ormalized with the following complex coefficients:

$$\underline{c}_k = \frac{\underline{I}(f_k)}{\underline{I}_0},\tag{5}$$

This normalization is illustrated by spectrum representation shown in Figure 2 [27].

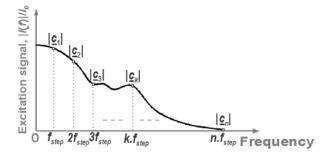


Figure 2: Extraction of the frequency spectrum coefficients from the excitation signal spectrum.

For the base band applications, it is interesting to note that the starting frequency f_{min} must be equal to the frequency step Δf . In this scope, the spectrum value can be extrapolated linearly to generate the DC-component of the excitation signal. According to the signal processing theory, the D C-component of the ultra-short transient signal is negligible at very low frequency band. So, the extrapolation operating will not change the calculation results. The upper frequency f_{max} must belong in the frequency bandwidth containing higher than 95% spectrum energy of the excitation signal.

Once, the frequency spectrum coefficients are defined, the time-dependent N F d ata co rresponding t o t he t ransient current signal c an b e c arried o ut b y c onvoluting the frequency co efficients \underline{c}_k and t he frequency-domain field data. The r outine p rocess will b e p resented i n the ne xt subsection.

2.2. Computational process of the proposed method

The c omputation method developed in t his p aper can be summarized in t wo s teps. After ex tracting t he frequency spectrum co efficient \underline{c}_k from t he transient e xcitation s ignal i(t) as explained in the previous subsection, we will focus on the co nvolution b etween f requency s pectrum co efficients and the frequency EM field data.

Let u s d enote $\underline{H}(x, y, z_0, f)$ the f requency d ependent magnetic f ield r ecorded i n t he p lane $z = z_0$ above t he considered r adiating el ectronic d evice as highlighted b y Figure 3.

The frequency EM field data $\underline{H}(x, y, z_0, f)$ can be obtained by 2D measurement s cans or s imulations with s tandard commercial tools.

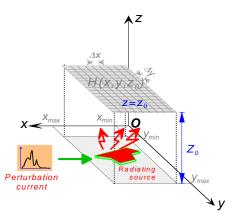


Figure 3: Representation of the magnetic NF scanned in the plane placed at the height z_0 above the radiating device.

In this case, we emphasize that the frequency EM field data $\underline{H}(x, y, z_0, f)$ needs t o b e s ynchronized with t he s pecific frequency interval $[f_{\min}, f_{\max}]$ of the transient excitation signal i(t) and t he frequency step Δf . A s pr esented i n Figure 3, th e magnetic N F ti me-dependent d ata $\underline{H}(x, y, z_0, t)$ is generated by the device u nder t est ex cited by the c urrent i(t). As argued above, the magnetic NF data $\underline{H}(x, y, z_0, t)$ can b e d etermined with t he I FFT by the convolution product of the frequency coefficient \underline{c}_k and the frequency d ependent N F d ata $\underline{H}(x, y, z_0, f)$ via th e following equation:

$$\underline{H}(x, y, z_0, t) = ifft[\underline{c}_k \cdot \underline{H}(x, y, z_0, t)], \qquad (6)$$

To reconstitute the time-domain results, the imaginary part of t he d ata $\underline{H}(x, y, z_0, t)$ is n ot n ecessary. T herefore, t he desired ti me-domain r esults ar e o btained with t he expression:

$$H(x, y, z_0, t) = \Re eal[\underline{H}(x, y, z_0, t)], \tag{7}$$

where the function $Real(\alpha)$ r epresents the r eal p art of the complex num ber α . The r outine pr ocess of the pr oposed computation method is presented in Figure 4 [35]. This work flow is performed with di fferent ope rations i n or der t o provide the time-domain E M N F r adiated b y the d evice under test with the arbitrary transient excitation signal i(t).

To validate the investigated method, a M atlab program has been i mplemented acco rding t o t he routine algorithm described in Figure 4.

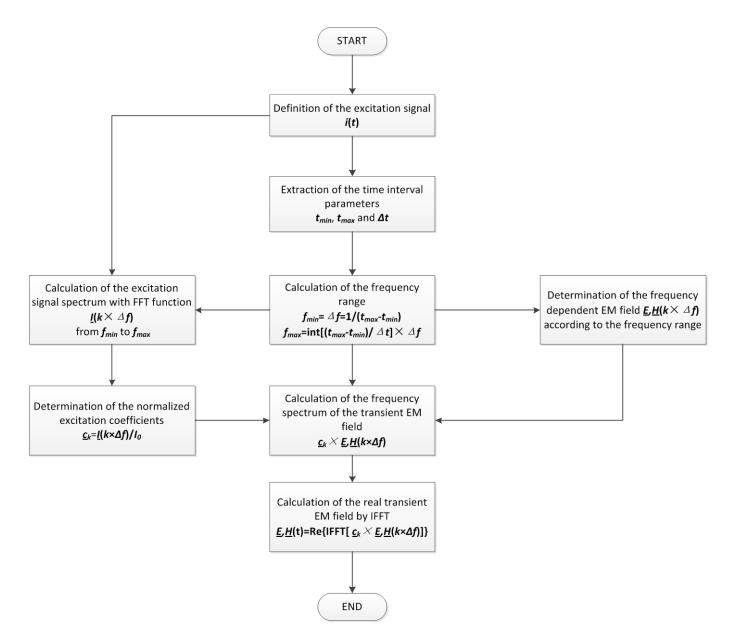


Figure 4: Routine process of the time-frequency computation method proposed [35].

2.3. Illustration results

In this subsection, a comparison between the transient EMfield radiated by a concrete microstrip device described from the 3 D s oftware s imulation and t hose o btained f rom the proposed method is realized.

2.3.1. Description of the Assumed Excitation Signal

In o rder t o hi ghlight t he i nfluence o f t he f orm a nd t he transient variation of the disturbing currents in the electronic structure, t he considered s hort-duration p ulse excitation current i(t) is assumed as a Gaussian signal modulating 1.25 GHz sine carrier, defined by the analytical formula:

$$i(t) = I_M \cdot \exp\left(-\frac{(t-t_0)^2}{2\Delta t^2}\right) \cdot \sin(2\pi f_0 t), \quad (8)$$

Figure 5 d isplays r espectively, t he transient p lot o f t his signal a nd its frequency s pectrum. In p ractice, t he t ime interval range is defined from $t_{min} = 0$ ns to $t_{max} = 14.218$ ns with step $\Delta t = 0.1436$ ns.

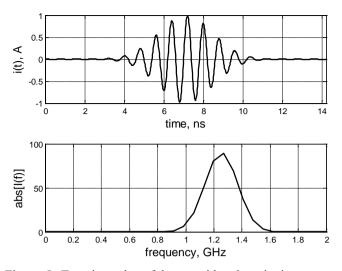


Figure 5: Transient p lot of the c onsidered e xcitation c urrent i(t) and its frequency spectrum I(f).

One can see that this modulated signal presents a frequency bandwidth of 0.5 GHz, where belongs more than 95-% of the spectrum s ignal e nergy. The cal culated d ata $\underline{I}(t) = ft[i(t)]$ implies the frequency coefficient v alues of i(t) according to the d efinition e xpressed in (8) as described ea rlier in subsection 2.2.

2.3.2 Description of the device under test

The microstrip circular resonator shown in F igure 6 was designed and considered as the device under test in order to validate the method under investigation. The r esonator is based on a substrate with relative permittivity $\varepsilon = 10$. It is fed by the via hole port with the transient current presented above. The top view of the resonator is shown by Figure 6.

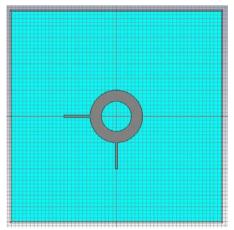


Figure 6: Top view of the microstrip circular resonator.

To validate the method proposed in this paper, comparisons of different r esults were made b etween t he C ST M icrowave simulations and the computation method proposed.

2.3.3. Transient EM-Field Determined by CST MWS simulation

By c onsidering the circular r esonator p resented in Figure 6, excited b y th e p ulse c urrent p lotted in F igure 5 y ields t he electric and magnetic field components mappings depicted in Figure 7 and Figure 8 at the arbitrary time $t_0 = 7.611$ ns and in the horizontal plan parallel to (*Oxy*) referenced by $z_0 = 2$ mm. The dimensions of the mappings were set at $L_x = 56$ mm and $L_y = 56$ mm with resolutions respectively, equal to $\Delta x = 1$ mm and $\Delta y = 1$ mm.

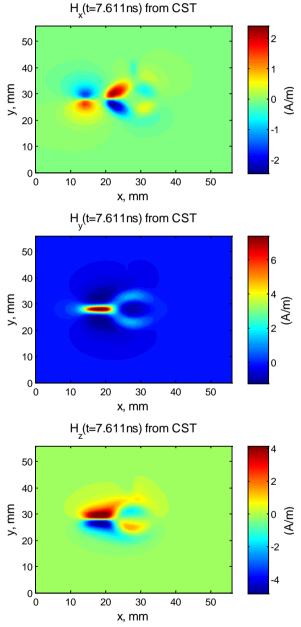


Figure 7: Cartographies of magnetic field components at t=7.611 ns obtained from the CST simulation.

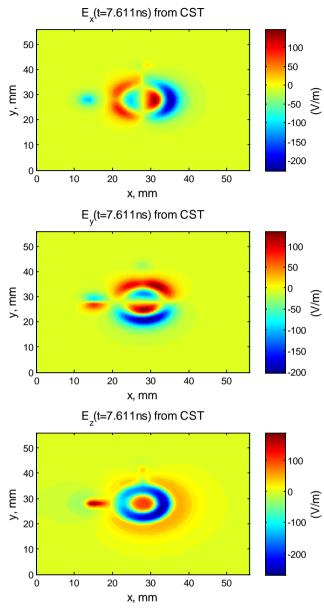


Figure 8 : C artographies of e lectric f ield components at t=7.611 ns obtained from the CST simulation.

2.3.4. Computed Results from the Proposed Method

First, by analyzing the frequency-domain results achieved by CST Microwave Studio, one obtains the cartographies of the frequency-dependent electric and magnetic field from $f_{min} = 1$ GHz to $f_{max} = 1.5$ GHz step $\Delta f = 0.01$ GHz.

After the program execution of the algorithm indicated by the flow chart described by Figure 4, one gets the results shown in Figure 9 and Figure 10 via the combination of the frequencydependent data of the electric or magnetic field components associated to the frequency coefficient of the excitation signal. One can see that one establishes the cartographies having the same behaviors as those generated via the direct calculations displayed in Figure 7 and Figure 8.

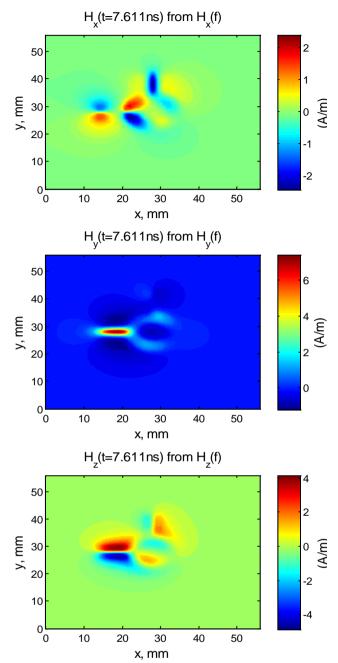


Figure 9: C artographies o f magnetic f ield components: obtained f rom t he pr oposed t ime-frequency c omputation method.

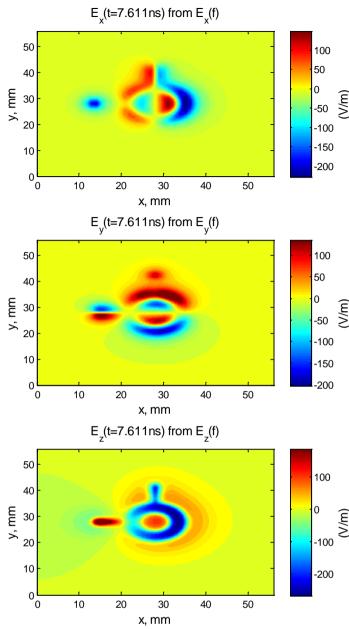


Figure 10: C artographies of electric f ield components: obtained f rom t he pr oposed t ime-frequency c omputation method.

Furthermore, as illustrated by Figure 11 and Figure 12, a very good correlation between the profiles along Ox ar Oy of the EM field components detected in the vertical plane placed at x = 22 mm or y = 30.3 mm was observed.

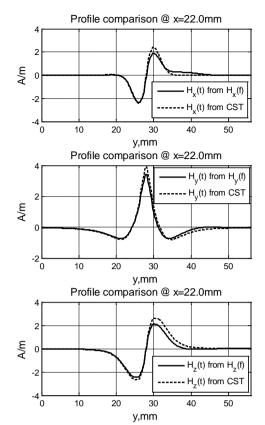


Figure 11: C omparisons of the magnetic field components profiles obt ained f rom t he pr oposed tim e-frequency computation method and the direct calculation, detected in the vertical plane x = 22mm.

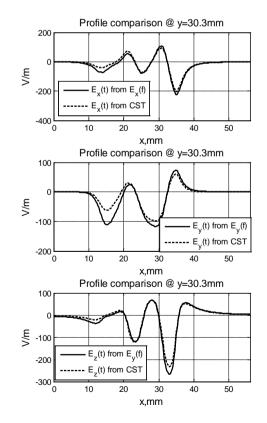


Figure 12: Co mparisons of the electric field components profiles obt ained f rom t he pr oposed t ime-frequency computation method and the direct calculation, detected in the vertical plane placed at y=30.3 mm.

In addition to this c omputation method, we propose further method e nabling t o e xtract t he t hird c omponent (along z direction) of EM fields in time-domain knowing the two first components (along x- and y- directions) in the next section.

3. Extraction method of the transverse component $X_z(t)$ from $X_x(f)$ and $X_y(f)$ with ultra-short duration transient perturbations

To reduce the order of complexity and the processing time of measurement, we propose a method to extract the time EM transversal component $X_z(t)$ from the known the longitudinal components $X_x(t)$ and $X_y(t)$. To do this, we use the Plane Wave Spectrum (PWS) method associated with the r adiation of electric dipoles in the time domain as introduced recently in [31-32].

The b asic ap proach o f E M f ield c haracterization in t ime domain i s ex tracted f rom t he f requency d ata co mbined via FFT. F irst, the PWS theory which was initially introduced in [36-38] w ill be a pplied t o t he obt ained da ta i n frequency domain. F inally, t he f requency d ata will b e transposed in to time domain with IFFT.

3.1. Principle of the time-frequency method of the zcomponent calculation from x-/y-components of the EM NF

By d efinition, the P WS m ethod [31-33][36-38] is a b asic method de dicated to the d ecomposition of a ny E M-field plotted in 2D as a sum of plane waves propagating in different space directions. One denotes:

$$\vec{k} = k_x \vec{u_x} + k_y \vec{u_y} + k_z \vec{u_z} , \qquad (9)$$

the wave vector in the rectangular coordinate system (*Oxyz*) with unit vectors, $\vec{u_x}$, $\vec{u_y}$ and $\vec{u_z}$. The modulus of this wave vector, what is also known as the wave number, is given by:

$$k(f) = \sqrt{k_x^2(f) + k_y^2(f) + k_z^2(f)} = \frac{2\pi}{\lambda(f)} = \frac{2\pi f}{\nu}.$$
 (10)

where $\lambda(f)$ is the wavelength at the operating f requency *f*. According to the PWS theory, the EM field $\vec{X}(x, y, z)$ can be expressed as a d ouble i ntegral of t heir P WS components $\vec{P}_X(k_x, k_y, z)$ with the following formulation:

$$\vec{X}(x, y, z) = \frac{1}{4\pi^2} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \vec{P}_X(k_x, k_y, z) e^{j(k_x x + k_y y)} dk_x dk_y . (11)$$

Similar to the 2D Fourier transform, the inverse PWS (IPWS) of EM field is given by the following equation:

$$\overrightarrow{P_X}(k_x,k_y,z) = \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} [\overrightarrow{X}(x,y,z)] e^{-j(k_x x + k_y y)} dx dy, \qquad (12)$$

The horizontal X-Y plane is with dimensions $L_x \times L_y$. It is discretized with the steps Δx and Δy , respectively, so that the discrete indexes, n_x and n_y are:

$$k_x = \frac{2\pi}{x} = \frac{2\pi}{n_x \Delta x},$$
(13)

$$k_y = \frac{2\pi}{y} = \frac{2\pi}{n_y \Delta y} \,. \tag{14}$$

In this case, the horizontal components of the wave vector k_x and k_y vary respectively between:

$$k_{x\min} = -\frac{\pi}{\Delta x}, \qquad (15)$$

$$k_{y\min} = -\frac{\pi}{\Delta y},$$
 (16)

and

$$k_{x\max} = \frac{\pi}{\Delta x},$$
 (17)

$$k_{y\max} = \frac{\pi}{\Delta y}, \qquad (18)$$

with the numerical step:

$$\Delta k_x = \frac{2\pi}{L_x},\tag{19}$$

$$\Delta k_y = \frac{2\pi}{L_y} \,. \tag{20}$$

From e quation (10), one cand etermine t he corresponding vertical component [31-33][36-38]:

$$k_{z} = \begin{cases} \sqrt{k^{2} - k_{x}^{2} - k_{y}^{2}} & \text{if } k_{x}^{2} + k_{y}^{2} < k^{2} \\ -j\sqrt{k_{x}^{2} + k_{y}^{2} - k^{2}} & \text{if } k_{x}^{2} + k_{y}^{2} > k^{2} \end{cases}.$$
(21)

To avoid the unexpected case, the following relation must be respected.

$$\max(\Delta k_x, \Delta k_y) < \frac{2\pi}{\lambda}.$$
 (22)

And also, at the boundary condition, the field components and their PWS components, $X_{x,y,z}$ and $P_{X_{x,y,z}}$ must tend to zero. According to the plane wave properties, wave vectors \vec{k} and

 \vec{P} must be perpendicular to each other:

$$\vec{k} \cdot \vec{P}_X = 0 \quad \Rightarrow \quad k_x P_{X_x} + k_y P_{X_y} + k_z P_{X_z} = 0.$$
(23)

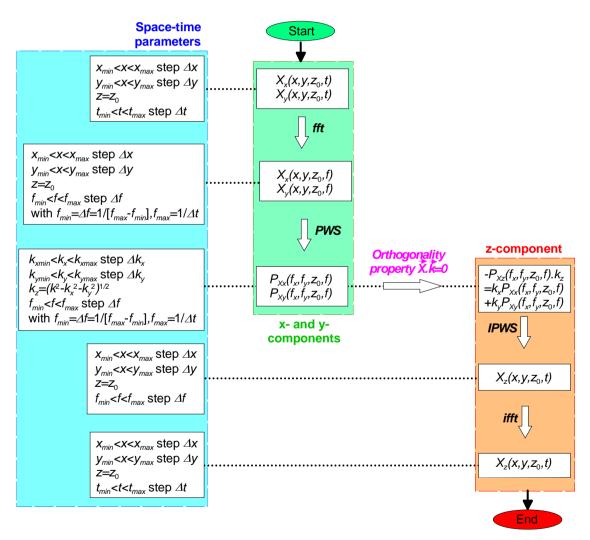


Figure 13: Routine algorithm illustrating the computation method of X_z from X_x and X_y by using the PWS transform.

So that, the vertical component P_{X_z} can be determined by the following equation:

$$P_{X_z} = -\frac{k_x P_{X_x} + k_y P_{X_y}}{k_z}.$$
 (24)

All the approaches and calculations presented above work in the f requency d omain. So, we need to transform the time domain d ata $X_x(t)$ and $X_y(t)$ into f requency domain by using the Fourier transform $X_{x,y}(f) = fft[X_{x,y}(t)]$. Also, at the end of t his p rocedure, the z-component $X_z(f)$ must b e t ransform back i nto time d omain by t he i nverse Fourier transform $X_z(t) = ifft[X_z(f)]$. F igure 1 1 s ummarizes t he r outine algorithm of the method proposed.

As a conclusion, all the procedure above means that P_{X_z} , obviously X_z , can be extracted from P_{X_x} and P_{X_y} which can be calculated from the IPWS equation expressed in (12) if the 2D data X_x and X_y are given. In summary, with the proposed method, the EM NF measurement processes can be simplified.

3.2. Application results

To validate the computation method proposed in this paper, a set of elementary electric dipoles with arbitrarily chosen configuration is placed in the X-Y plane as displayed in Figure 14. It is considered as a radiating source defined by analytical equations proposed in [39-41]. All the electric dipoles a re simultaneously excited by the same time varying current I(t). Figure 15 displays the c urrent e xcitation. The f requency spectrum of I(t) plotted in F igure 16 presents a maximum frequency of about 5 GHz.

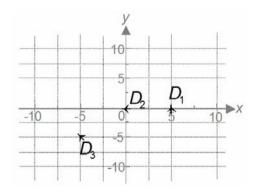


Figure 14: Assumed configuration of the set of three electric dipoles.

So, the minimum wave length is $\lambda_{min} = c/f_{max} = 0.6$ m. According to the wave propagation theory, the NF zone is up to about $\lambda_{min}/10 = 6$ cm above the dipoles plane.

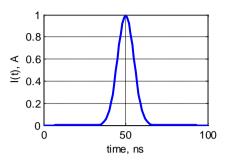


Figure 15: Time variation of the excitation signal.

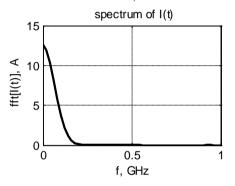


Figure 16: Frequency spectrum of t he excitation signal I(t) shown in Figure 15.

First, w e w ill calculate the tr ansient e lectric fields with formulae expressed in [39-40]. The results are shown in Figure 17, the plots plane is at the height z = 10 mm and at the time $t_0 = 50$ ns. The profile of the Electric field along the line equated by x = 0 mm is shown by F igure 18. The three transient electric field components ar e o btained at the three different point in the plane z = 10 mm, shown as Figure 19.

Second, the vertical electric field component $E_z(t)$ extracted by the P WS m ethod w ill be compared w ith the own $E_z(t)$ calculated directly. This comparison is shown by Figure 19. The comparison of the E_z distribution at t = 50 ns a cross the horizontal plane at z = 10 mm, is shown in Figure 20. One can see a good ag reement in the zone w ith hi gher field strengths with almost the same distribution.

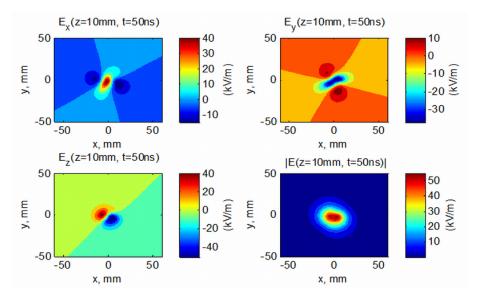


Figure 17: Calculated electric field components E_x , E_y and E_z and the total magnitude |E| for the dipoles in Figure 14 at the horizontal plane at the height z = 10 mm at the instant time t = 50 ns.

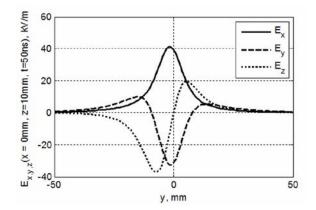


Figure 18: Calculated electric field components E_x , E_y and E_z for the dipoles in Figure 14 along the line z = 10 mm, x = 0 and at the instant time t = 50 ns.

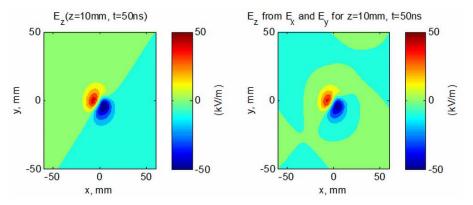


Figure 19: Comparison between the E_z components directly computed and extracted at the instant time t = 50 ns across the horizontal plane at z = 10 mm.

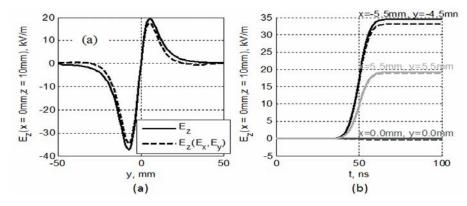


Figure 20: Comparison between directly computed and extracted E_z field: (a) at the instant time t = 50 ns along the line z = 10 mm, x = 0; (b) as a function of time at the points (x,y) = {(0,0), (-5.5mm,-4.5mm), (5.5mm,4.5mm)} on the horizontal plane at z = 10mm.

We can also find some errors in the zone with lower field strengths. However, these errors are relatively small. They can be visualised in Figure 20. We can see that the relative errors are very small at the randomly chosen points.

In order to verify the relevance of the proposed method, we also simulate the transient radiation of the set of dipoles in Figure 14 with commercial 3D EM modelling software, CST Microwave S tudioTM. Figure 21 describes the setup of the electric dipoles in CST MWS simulation.

The results of simulations with CST MWS are displayed in Figures 22.

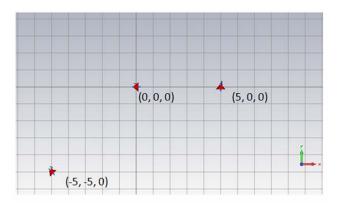


Figure 21: CST MWS simulation setup for the three dipoles from Figure 14.

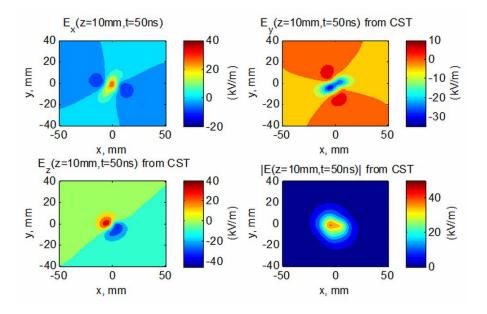


Figure 22: Simulated electric field components E_x , E_y and E_z and the total magnitude |E| for the dipoles in Figure 14 at the horizontal plane at the height z = 10 mm at the instant time t = 50 ns.

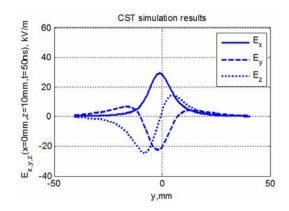


Figure 23: Simulated electric field components E_x , E_y and E_z for the dipoles in Figure 21 along the line z = 10 mm and x = 0 and at the instant time t = 50 ns.

Through these figures, we can see that the simulations and calculation r esults present a v ery g ood co rrelation. T he almost same field distributions are found. However, we can find some differences in the magnitude, when we compare the simulation and calculation results. These differences can be considered as t he p roblem of t he mesh s izes of t he considered EM simulator.

4. Conclusions

The methodology of time-frequency EM NF computation is successfully developed in this paper. The method proposed consists mainly in c onvoluting the E M NF o btained from frequency calculation, simulations or measurements in wide frequency b and a nd a ny t ransient a rbitrary wave f orm perturbations.

In the first part of the paper, theoretical approach illustrating the r outine a lgorithm of t he method is e stablished. Then, application by comparing simulations of a microwave device with a standard co mmercial t ool an d s emi-analytical calculations r un i n M atlab p rogramming e nvironment was made t o ve rify t he va lidity of t he method. T o do t his, a transient current with pulse wave form presenting s ome n s time-duration was co nsidered. A s ex cepted a g ood correlation with r esults f rom a nalytical c alculation w as found.

In t he s econd part of the paper, a t ransposition of a frequency method based on the PWS spectrum is presented.

The flow chart summarizing the computation of E M wave component X_z from X_x and X_y in 2 D is explained. Then, application with the radiation of set of EM dipoles is presented. Once again, as expected a v ery good correlation with ti me-domain r esults f rom a 3 D E M s imulation commercial tool is performed.

The approach introduced in this paper can be very useful for time domain EM near field modeling and characterization in EMC a pplication. The m ethod es tablished i s cu rrently extended for the modeling of EM NF emissions based on the set of elementary dipoles [41] based on the frequency models developed in [7-8].

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